

# A3V26S004N

## Airfast RF Power LDMOS Transistor

Rev. 0 — December 2020

Data Sheet: Technical Data

This 26 dBm RF power LDMOS transistor is designed for cellular base station applications covering the frequency range of 2496 to 2690 MHz.

### 2600 MHz

- Typical Single-Carrier W-CDMA Reference Circuit Performance:  
 $V_{DD} = 42 \text{ Vdc}$ ,  $I_{DQ} = 17 \text{ mA}$ ,  $P_{out} = 23.5 \text{ dBm Avg.}$ , Input Signal PAR = 9.9 dB @ 0.01% Probability on CCDF.(1)

Frequency	$G_{ps}$ (dB)	$\eta_D$ (%)	Output PAR (dB)	ACPR (dBc)
2515 MHz	23.2	15.1	10.3	-35.0
2595 MHz	23.0	15.5	9.6	-37.0
2675 MHz	22.0	14.8	9.3	-37.7

- All data measured in reference circuit with device soldered to printed circuit board.

### Features

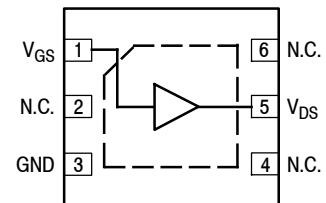
- Designed for low complexity analog or digital linearization systems
- Universal broadband driver
- Optimized for massive MIMO active antenna systems for 5G base stations

## A3V26S004N

2496–2690 MHz, 26 dBm Avg., 48 V  
AIRFAST RF POWER LDMOS  
TRANSISTOR



DFN 4.5 x 4  
PLASTIC



(Top View)

Note: Exposed backside of the package is the source terminal for the transistor.

**Figure 1. Pin Connections**

**Table 1. Maximum Ratings**

Rating	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	-0.5, +105	Vdc
Gate-Source Voltage	$V_{GS}$	-6.0, +10	Vdc
Operating Voltage	$V_{DD}$	55, +0	Vdc
Storage Temperature Range	$T_{stg}$	-65 to +150	°C
Case Operating Temperature Range	$T_C$	-40 to +150	°C
Operating Junction Temperature Range (1,2)	$T_J$	-40 to +225	°C

**Table 2. Thermal Characteristics**

Characteristic	Symbol	Value (2,3)	Unit
Thermal Resistance, Junction to Case Case Temperature 125°C, 26.0 dBm Avg., W-CDMA, 48 Vdc, $I_{DQ} = 17$ mA, 2595 MHz	$R_{\theta JC}$	8.0	°C/W

**Table 3. ESD Protection Characteristics**

Test Methodology	Class
Human Body Model (per JS-001-2017)	1C
Charge Device Model (per JS-002-2014)	C2a

**Table 4. Moisture Sensitivity Level**

Test Methodology	Rating	Package Peak Temperature	Unit
Per JESD22-A113, IPC/JEDEC J-STD-020	3	260	°C

**Table 5. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>Off Characteristics</b>					
Zero Gate Voltage Drain Leakage Current ( $V_{DS} = 105$ Vdc, $V_{GS} = 0$ Vdc)	$I_{DSS}$	—	—	10	$\mu\text{Adc}$
Zero Gate Voltage Drain Leakage Current ( $V_{DS} = 55$ Vdc, $V_{GS} = 0$ Vdc)	$I_{DSS}$	—	—	1	$\mu\text{Adc}$
Gate-Source Leakage Current ( $V_{GS} = 8$ Vdc, $V_{DS} = 0$ Vdc)	$I_{GSS}$	—	—	1	$\mu\text{Adc}$
<b>On Characteristics</b>					
Gate Threshold Voltage ( $V_{DS} = 10$ Vdc, $I_D = 10$ $\mu\text{Adc}$ )	$V_{GS(th)}$	0.7	1.2	1.7	Vdc
Gate Quiescent Voltage ( $V_{DD} = 48$ Vdc, $I_D = 16$ mAdc, Measured in Functional Test)	$V_{GS(Q)}$	1.6	1.78	1.9	Vdc
Drain-Source On-Voltage ( $V_{GS} = 10$ Vdc, $I_D = 75$ mAdc)	$V_{DS(on)}$	0.2	0.6	0.9	Vdc

1. Continuous use at maximum temperature will affect MTTF.

2. MTTF calculator available at <http://www.nxp.com>.

3. Refer to AN1955, *Thermal Measurement Methodology of RF Power Amplifiers*. Go to <http://www.nxp.com/RF> and search for AN1955.

(continued)

**Table 5. Electrical Characteristics** ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (continued)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>Functional Tests</b> <sup>(1)</sup> (In NXP Production Test Fixture, 50 ohm system) $V_{DD} = 48\text{ Vdc}$ , $I_{DQ} = 16\text{ mA}$ , $P_{out} = 26\text{ dBm Avg.}$ , $f = 2690\text{ MHz}$ , 1-tone CW.					
Power Gain	$G_{ps}$	19.5	23.3	26.0	dB
Drain Efficiency	$\eta_D$	18.0	21.9	—	%
$P_{out}$ @ 6 dB Compression Point	P6dB	33.5	35.0	—	dBm

**Wideband Ruggedness** (In NXP Reference Circuit, 50 ohm system)  $I_{DQ} = 17\text{ mA}$ ,  $f = 2595\text{ MHz}$ , Additive White Gaussian Noise (AWGN) with 10 dB PAR

ISBW of 400 MHz at 55 Vdc, 1.5 W Avg. Modulated Output Power (3 dB Input Overdrive from 0.7 W Avg. Modulated Output Power)	No Device Degradation
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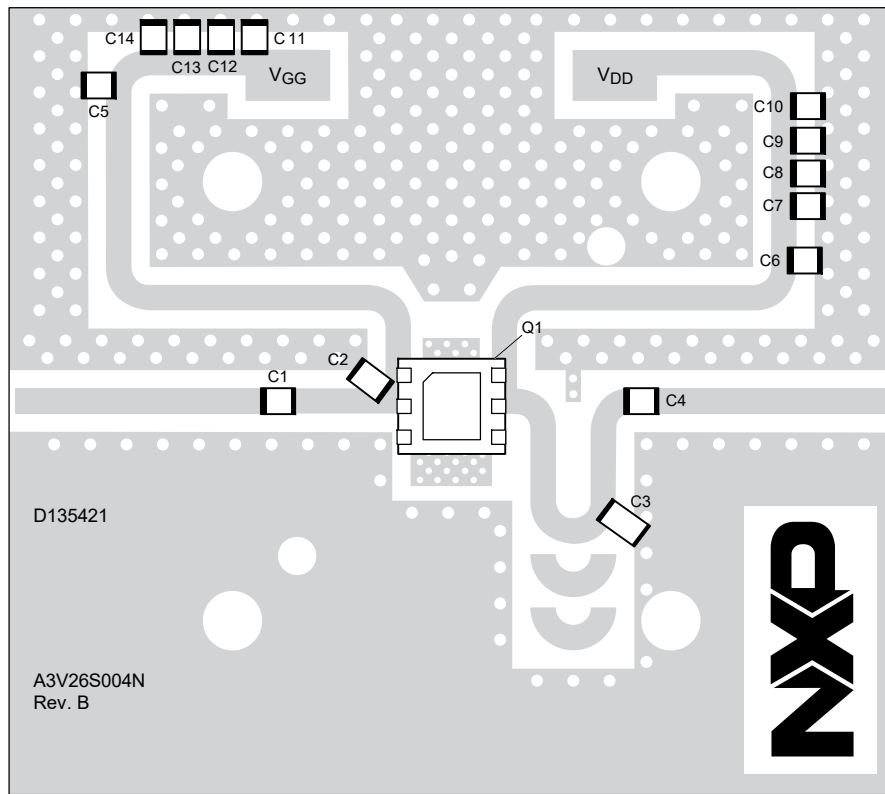
**Typical Performance** <sup>(2)</sup> (In NXP Reference Circuit, 50 ohm system)  $V_{DD} = 42\text{ Vdc}$ ,  $I_{DQ} = 17\text{ mA}$ , 2515–2675 MHz Bandwidth

VBW Resonance Point (IMD Third Order Intermodulation Inflection Point)	$VBW_{res}$	—	170	—	MHz
Gain Flatness in 160 MHz Bandwidth @ $P_{out} = 23.5\text{ dBm Avg.}$	$G_F$	—	0.7	—	dB
<b>Fast CW, 27 ms Sweep</b>					
$P_{out}$ @ 3 dB Compression Point	P3dB	—	3.1	—	W
AM/PM (Maximum value measured at the P3dB compression point across the 2515–2675 MHz bandwidth)	$\Phi$	—	–23	—	°
Gain Variation over Temperature (–40°C to +85°C)	$\Delta G$	—	0.017	—	dB/°C
Output Power Variation over Temperature (–40°C to +85°C)	$\Delta P_{1dB}$	—	0.004	—	dB/°C

**Table 6. Ordering Information**

Device	Tape and Reel Information	Package
A3V26S004NT6	T6 Suffix = 5,000 Units, 12 mm Tape Width, 13–inch Reel	DFN 4.5 × 4

1. Part internally input matched.
2. All data measured in fixture with device soldered to printed circuit board.



Note: All data measured in reference circuit with device soldered to printed circuit board. *aaa-037822*

**Figure 2. A3V26S004N Reference Circuit Component Layout**

**Table 7. A3V26S004N Reference Circuit Component Designations and Values**

Part	Description	Part Number	Manufacturer
C1	6.8 pF Chip Capacitor	600F6R8BW250XT	ATC
C2	1.0 pF Chip Capacitor	600F1R0BW250XT	ATC
C3	1.8 pF Chip Capacitor	600F1R8BW250XT	ATC
C4	10 pF Chip Capacitor	600F100FW250XT	ATC
C5, C6	20 pF Chip Capacitor	600F200FW250XT	ATC
C7	0.1 $\mu$ F Chip Capacitor	GRM319R71H104KA	Murata
C8	1 $\mu$ F Chip Capacitor	GRM32ER72A105KA	Murata
C9, C10	10 $\mu$ F Chip Capacitor	GRM31CR61H106KA	Murata
C11	10 $\mu$ F Chip Capacitor	GRM21BR61C106KE	Murata
C12	1 $\mu$ F Chip Capacitor	08055C105KAT2A	AVX
C13	0.1 $\mu$ F Chip Capacitor	GRM188R71H104KA	Murata
C14	2.2 nF Chip Capacitor	GRM1885C1H222JA	Murata
Q1	RF Power LDMOS Transistor	A3V26S004N	NXP
PCB	Rogers RO4350B, 0.020", $\epsilon_r = 3.66$	D135421	MTL

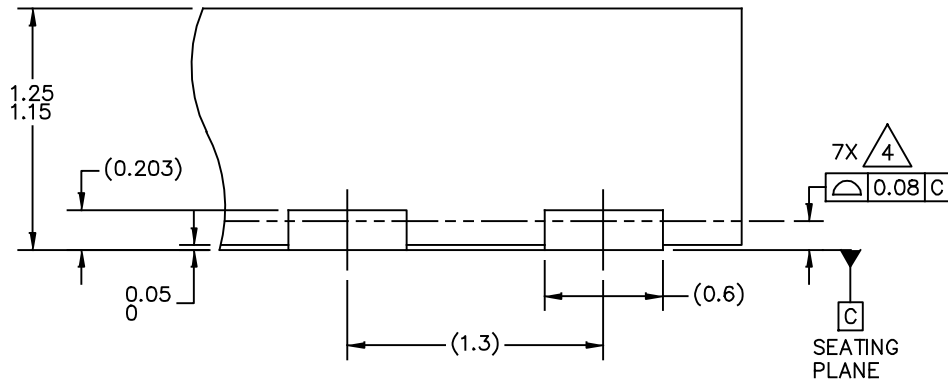


**Figure 3. Product Marking**



H-PDFN-6 I/O  
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



DETAIL E  
VIEW ROTATED 90°CW

RELEASED FOR EXTERNAL ASSEMBLY ONLY. THIS DESIGN ONLY MEETS EXTERNAL DESIGN AND ASSEMBLY RULES. MUST BE REVIEWED AND UPDATED BEFORE BEING ASSEMBLED INTERNALLY.

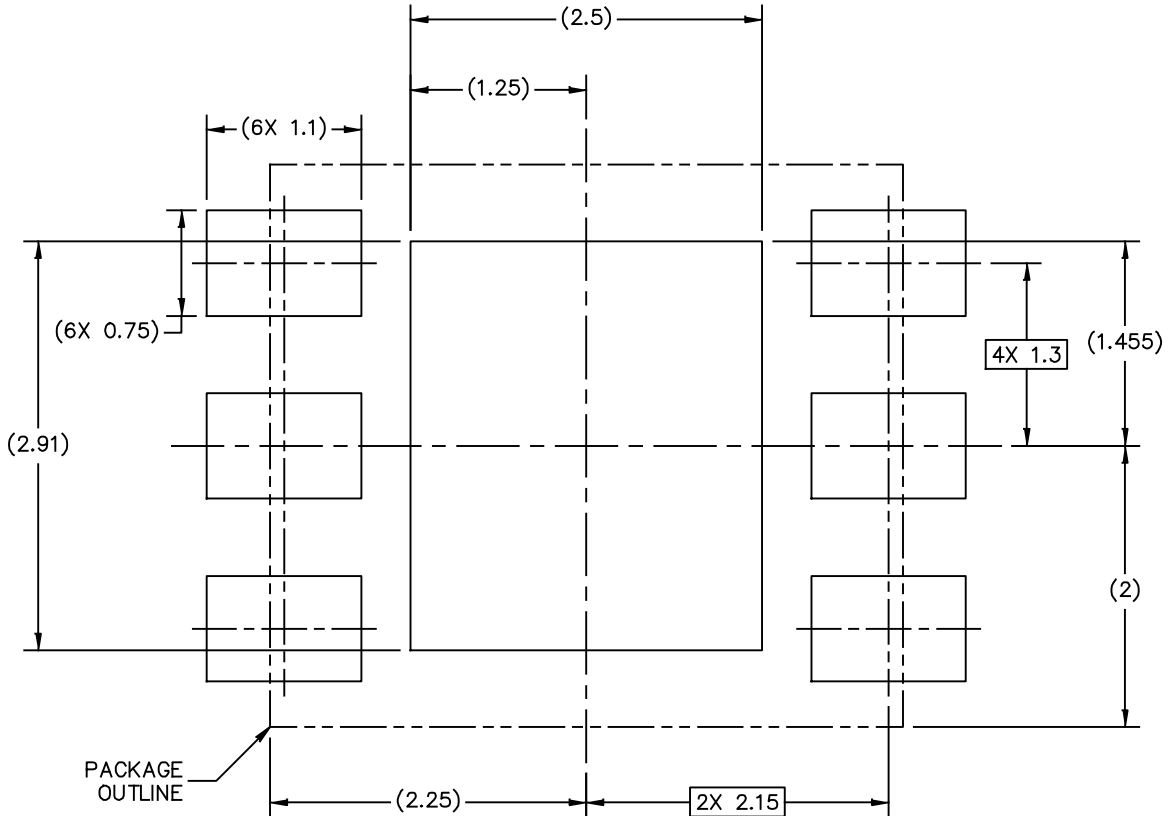
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H-PDFN-6 I/O  
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



PCB DESIGN GUIDELINES – SOLDER MASK OPENING PATTERN

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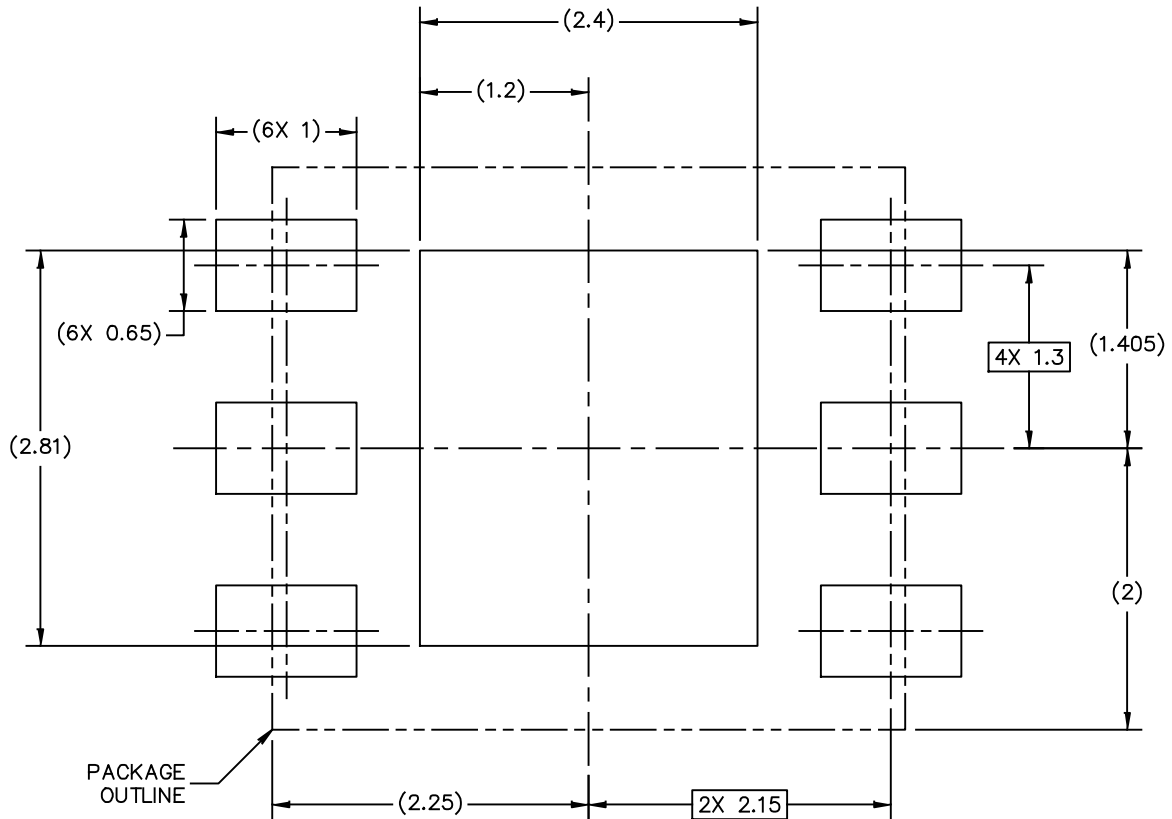
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H-PDFN-6 I/O  
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



PCB DESIGN GUIDELINES – I/O PADS AND SOLDERABLE AREA

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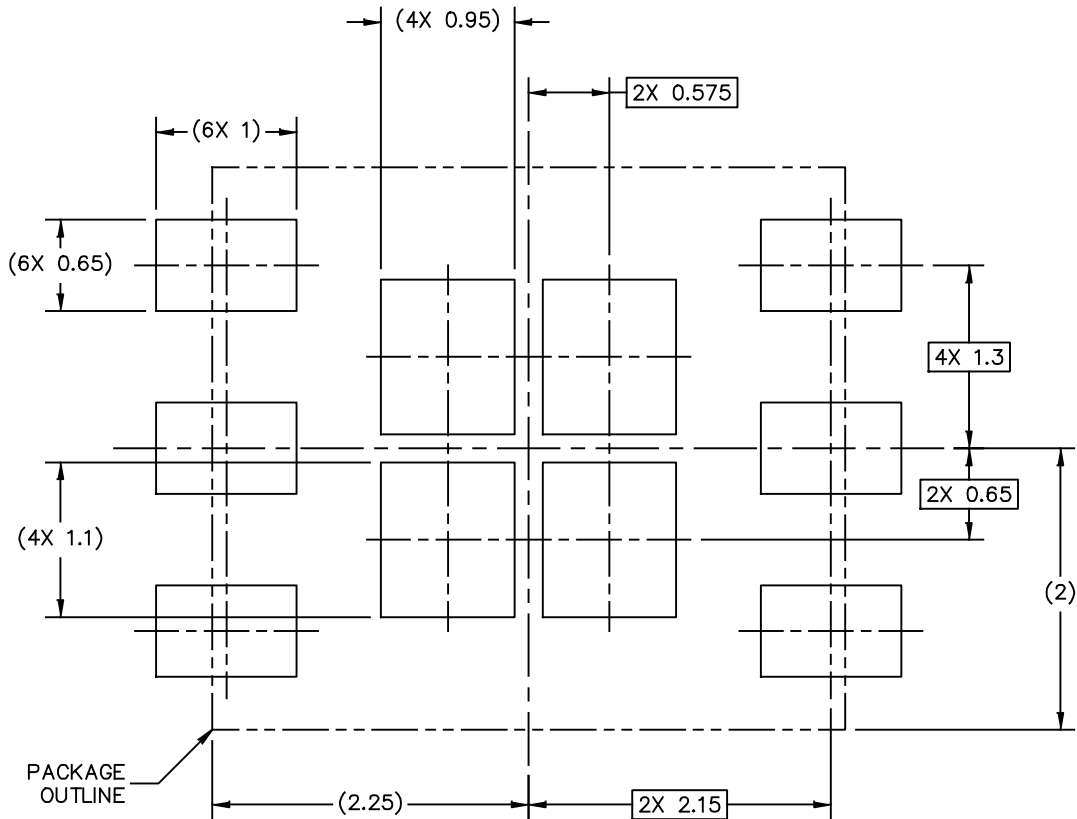
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H-PDFN-6 I/O  
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1



RECOMMENDED STENCIL THICKNESS 0.125 OR 0.15

PCB DESIGN GUIDELINES – SOLDER PASTE STENCIL

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H-PDFN-6 I/O  
4.5 X 4.0 X 1.2 PKG, 1.3 PITCH

SOT2040-1

## NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. PIN 1 FEATURE SHAPE, SIZE AND LOCATION MAY VARY.
4. COPLANARITY APPLIES TO LEADS AND DIE ATTACH FLAG.

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## Product Documentation, Software and Tools

Refer to the following resources to aid your design process.

### Application Notes

- AN1907: Solder Reflow Attach Method for High Power RF Devices in Plastic Packages
- AN1955: Thermal Measurement Methodology of RF Power Amplifiers

### Software

- Electromigration MTTF Calculator
- .s2p File

### Development Tools

- Printed Circuit Boards

## Revision History

The following table summarizes revisions to this document.

Revision	Date	Description
0	Dec. 2020	<ul style="list-style-type: none"><li>• Initial release of data sheet</li></ul>

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